

Features

- Peak Output Current: IOP = ±2.5A (max)
- Threshold Input Current: IFLH = 5 mA (max)
- Common mode transient immunity : ±25kV/µs (min)
- Under voltage lock out (UVLO) protection with hysteresis
- RoHS and REACH Compliance
- Halogen Free Compliance
- Regulatory Approvals
 - ✓ UL UL1577 (E364000)
 - ✓ VDE EN60747-5-5(VDE0884-5)
 - ✓ CQC GB4943.1, GB8898(14001104999)
 - ✓ IEC62368 (FI/41119)

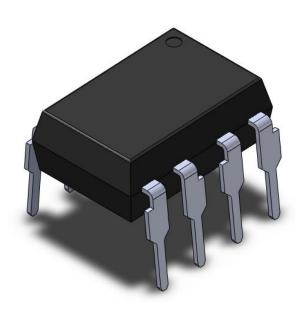
Description

The CT3120 consists of a LED optically coupled to an integrated circuit with a power output stage. This optocoupler is ideally suited for driving power IGBTs and MOSFETs used in motor control inverter applications. The high operating voltage range of the output stage provides the drive voltages required by gate-controlled devices.

Applications

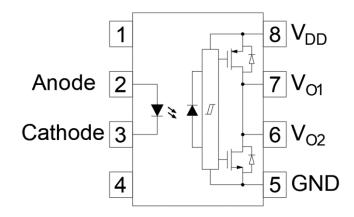
- Isolated IGBT/Power MOSFET gate drive
- Industrial Inverter
- AC brushless and DC motor drives
- Induction Heating

Package Outline



Note: Different lead forming options available. See package dimension.

Schematic



Truth Table

LED	V _{CC} -V _{EE} Positive Going	V _{CC} -V _{EE} Negative Going	Output
Off	0 to 30 V	0 to 30V	Low
On	0 to 11.0V	0 to 9.5V	Low
On	11.0 to 13.5V	9.5 to 12V	Transition
On	13.5 to 30V	12 to 30V	High



Absolute Maximum Ratings $T_A = 25^{\circ}C$, unless otherwise specified

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage (AC, 1 minute, 40 ~ 60% R.H.)	5000	V _{RMS}	1
Topr	Operating temperature	-40 ~ +110	οС	
Тѕтс	Storage temperature	-55 ~ +125	°C	
Tsol	Soldering temperature (For 10 seconds)	260	°C	2
PT	Total Power Dissipation	300	mW	
Emitter				
I _F	Forward current	25	mA	
I _{FP}	Peak forward current (50% duty, 1ms P.W)	1	А	
V _R	Reverse voltage	5	V	
Detector				
P _D	Power dissipation	250	mW	
V _{O(PEAK)}	Peak Output Voltage	0 to 30	V	3
Іорн	Output High Peak Current	2.5		4
IOPL	Output Low Peak Current	2.5	A	4
Vcc	Supply voltage	0 to 30	V	

Notes

- 1. AC for 1 minute, $RH = 40 \sim 60\%$.
- 2. For 10 second peak
- 3. The $V_{O(PEAK)}$ voltage CAN NOT BE high than V_{CC} .
- 4. The I_0 maximum pulse width = 10 μ s, maximum duty cycle = 0.2%.



Electrical Characteristics

Over recommended operating conditions TA = -40 to 110 °C.

Typical values are measured at V_{CC} =30V, V_{EE} = GND, T_A = 25°C (unless otherwise stated)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	IF = 10mA	-	1.45	1.8	V	
VR	Reverse Voltage	IR = 10μA	5.0	-	-	V	
$\Delta V_F/\Delta T_A$	Temperature coefficient of forward	IF =10mA	_	-1.8	_	mV/°C	
ΔVF/ΔIA	voltage	11 – 10111A	_	-1.0	_	11107 C	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
ICCL	Logic Low Supply Current	V _F = 0 to 0.8V, V _O = Open	-	1.5	5	mA	
Іссн	Logic High Supply Current	I _F = 7mA to 10mA, V _O = Open	-	1.5	5	IIIA	

Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
V	High Level Output Voltage	I _F = 10mA, I _O = -2.5A	Vcc - 6	-	-		
V _{OH}		I _F = 10mA, I _O = -100mA	V _{CC} - 4	-	-	V	
		I _F = 0mA, I _O = 2.5A	-	-	V _{EE} + 6	.,	
V _{OL}	Low Level Output Voltage	I _F = 0mA, I _O = 100mA	-	-	V _{EE} + 4	V	
,	High Level Output Current	V _O = V _{CC} -3V	-	-	-1	А	1
Іорн		Vo= Vcc-6V	-	-	-2		1
		Vo= VEE+3V	1	-	-		1
IOPL	Low Level Output Current	Vo= VEE+6V	2	-	-	Α	1
I _{FLH}	Input Threshold Current	I _O = 0mA, V _O > 5V	-	1.4	5.0	mA	
V _{FHL}	Input Threshold Voltage	I _O = 0mA, V _O < 5V	0.8	-	-	V	
V _{UVLO+}	Under Voltage Lockout	I _O = 10mA, V _O > 5V	11	-	13.5	M	
V _{UVLO} -	Threshold	Io= 10mA, Vo< 5V	9.5	-	12.0	V	

Notes

1. The I_0 maximum pulse width = 10 μ s, maximum duty cycle = 0.2%.



Electrical Characteristics

Over recommended operating conditions TA = -40 to 110 °C.

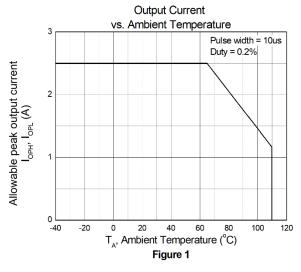
Typical values are measured at V_{CC} =30V, V_{EE} = GND, T_A = 25°C (unless otherwise stated)

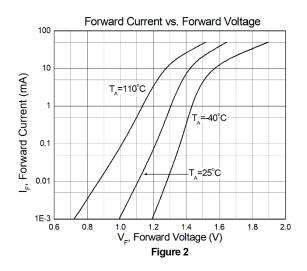
Switching Characteristics

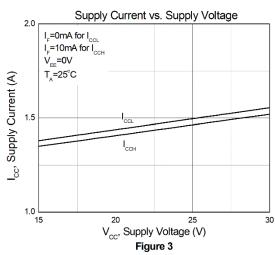
Symbol	Parameters	Test C	onditions	Min	Тур	Max	Units	Notes
T _{PHL}	High to Low Propagation Delay			100	180	500	ns	
T _{PLH}	Low to High Propagation Delay	1 7 to 10 to 1	. C. 40=E D	100	140	500	ns	
P _{WD}	Pulse Width Distortion				40	300	ns	
t PSK	Propagation Delay Skew					40	ns	
t _r	Rise Time				20		ns	
t _f	Fall Time				20		ns	
tuvlo(ON)	UVLO Turn On Delay	I _F = 10mA, V _O	> 5V		3.5		μs	
tuvlo(off)	UVLO Turn Off Delay	I _F = 10mA, V _O	< 5V		3		μs	
CM _H	Common Mode Transient High	$V_{CC}=30V$, $T_{A}=25$ ^{0}C ,	I _F = 7 to 16mA	25			kV/μs	
CM _L	Common Mode Transient Low	V _{CM} = 1.5kV	I _F = 0mA	25			kV/μs	

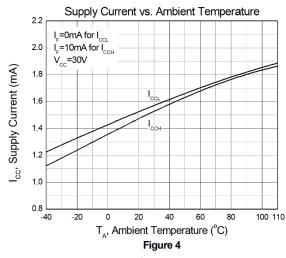


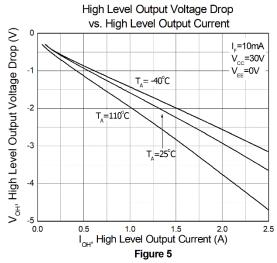
Typical Characteristic Curves $T_A = 25$ °C, unless otherwise specified

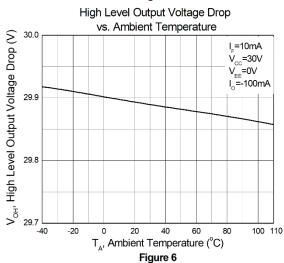






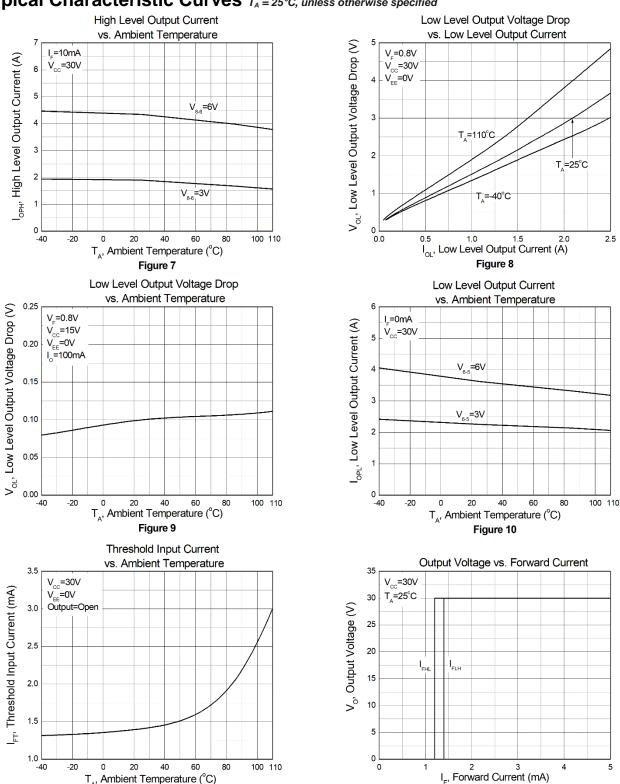








Typical Characteristic Curves $T_A = 25$ °C, unless otherwise specified



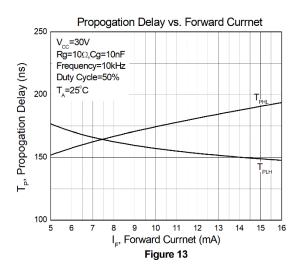
Typical Characteristic Curves $T_A = 25$ °C, unless otherwise specified

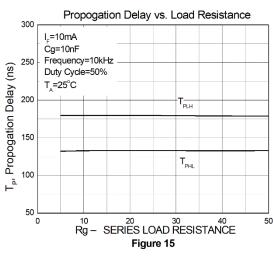
T_A, Ambient Temperature (°C)

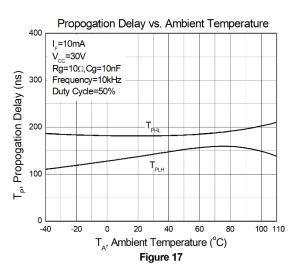
Figure 11

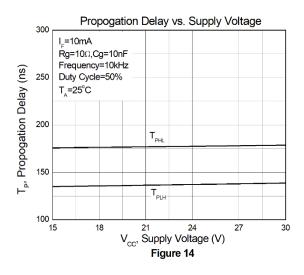
Figure 12

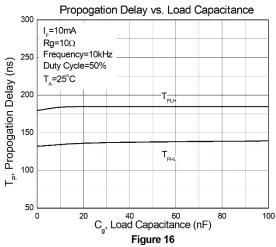








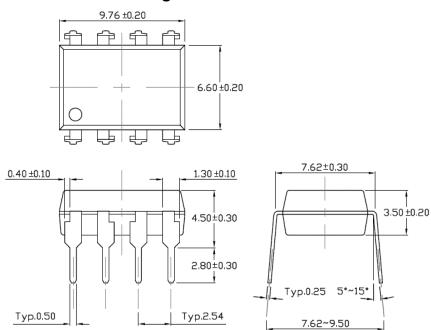




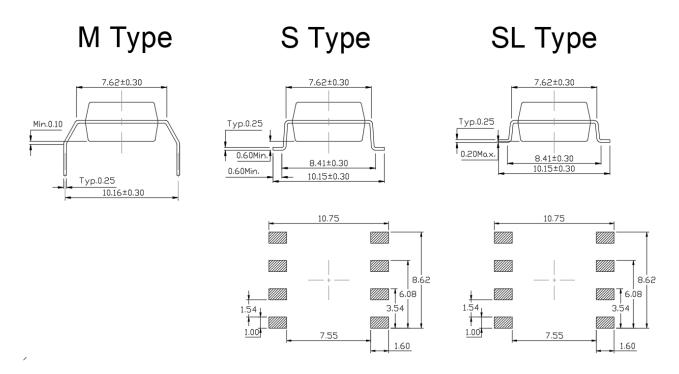


Package Dimension Dimensions in mm unless otherwise stated

Standard DIP - Through Hole

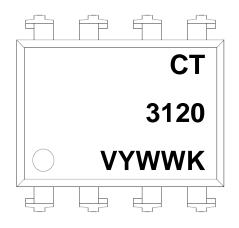


Forming Option Dimensions in mm unless otherwise stated





Marking Information



Note:

CT : Denotes "CT Micro"

3120 : Part Number

V : VDE Safety Mark Option (Blank or V)

Y : One Digit Year CodeWW : Two Digit Work WeekK : Manufacturing Code

Ordering Information

CT350(V)(Y)(Z)

CT = Denotes "CT Micro"

3120 = Part Number

V = VDE Safety Mark Option (Blank or V)

Y = Lead Form Option (S, SL, M or Blank)

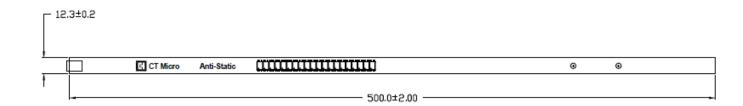
Z = Tape and Reel Option (Blank, T1 or T2)

Option	Description	Quantity
None	Standard 8 Pin Dip	40 Units/Tube
M	Gullwing (400mil) Lead Forming	40 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1000 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1000 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming– With Option 1 Taping	1000 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming – With Option 2 Taping	1000 Units/Reel

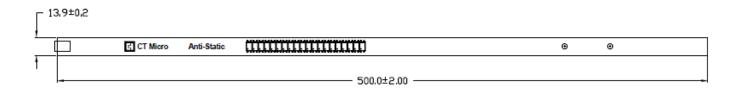


Carrier Specifications Dimensions in mm unless otherwise stated

Tube Option Standard DIP

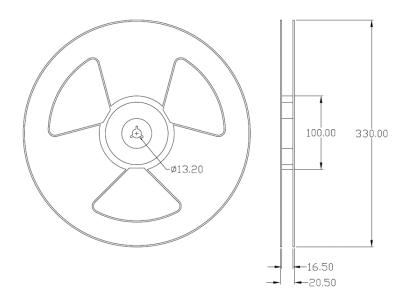


Tube Option M Type



Reel Dimension All dimensions are in mm, unless otherwise stated

Option S(T1/T2) & SL(T1/T2)

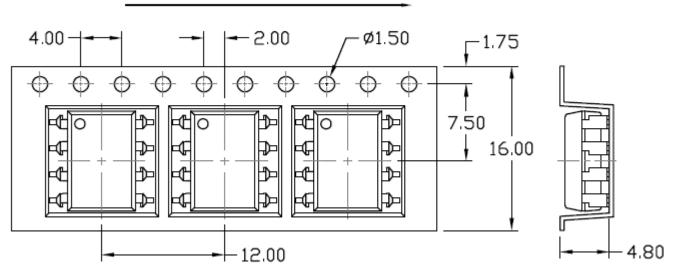




Carrier Tape Specifications Dimensions in mm unless otherwise stated

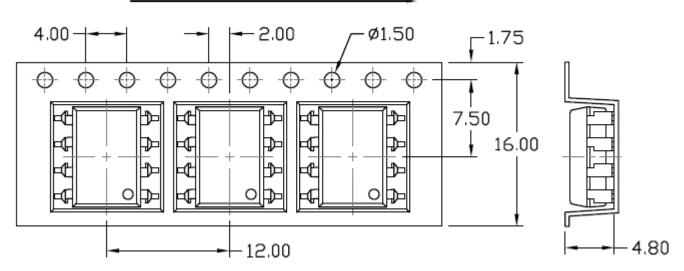
Option S(T1) & SL(T1)

Input Direction



Option S(T2) & SL(T2)

Input Direction





Solderability spec (Follow the JEDEC standard JESD22-B102)

Reflow Soldering: Immersed surface, other than the end of pin as cut-surface, must be covered by solder.

Solder-Bath: More than 95% of the electrode must be covered with solder.

Wave soldering (Follow the JEDEC standard JESD22-A111)

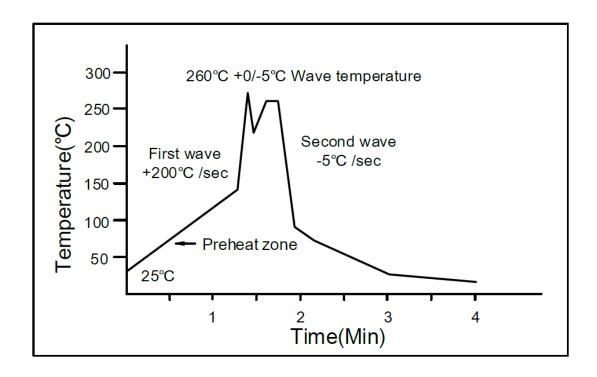
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature: 25 to 140°C.

Preheat time: 30 to 80 sec.



Iron soldering (Follow the standard MIL-STD 202G, Method 210F)

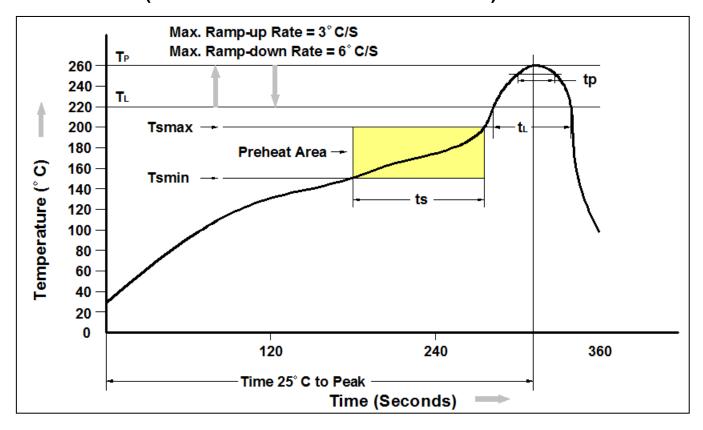
Allow single lead soldering in every single process.

One time soldering is recommended. Temperature: 350±10°C

Time: 5 sec max.



Reflow Profile (Follow the JEDEC standard J-STD-020)



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.





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